

Isc N-Channel MOSFET Transistor

IRFS3207Z

• FEATURES

- With To-263(D2PAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

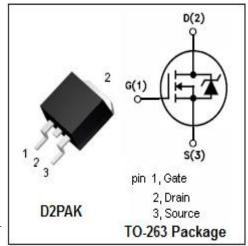
· Switching applications

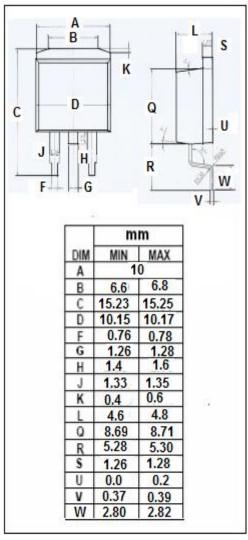
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	75	V	
V _{GSS}	Gate-Source Voltage	±20	V	
I _D	Drain Current-ContinuousTc=25℃ Tc=100℃	170 120	Ι Δ	
І _{ОМ}	Drain Current-Single Pulsed	670	А	
P _D	Total Dissipation @T _c =25℃	300	W	
T _{ch}	Max. Operating Junction Temperature	175	$^{\circ}$	
T _{stg}	Storage Temperature	-55~175	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.5	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT			
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	75			V			
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.15mA	2.0		4.0	V			
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =75A		3.3	4.1	mΩ			
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±100	nA			
I _{DSS}	Drain-Source Leakage Current	V _{DS} =75V; V _{GS} = 0V;Tj=25°C V _{DS} =75V; V _{GS} = 0V;Tj=125°C			20 250	μА			
V _{SDF}	Diode forward voltage	I _{SD} =75A, V _{GS} = 0 V			1.3	V			



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